

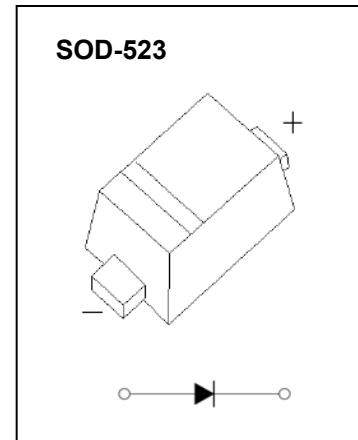
FAST SWITCHING DIODE

SOD-523 Plastic-Encapsulate Diodes

FEATURES

- Small Package
- Low Reverse Current
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion

MARKING: T5

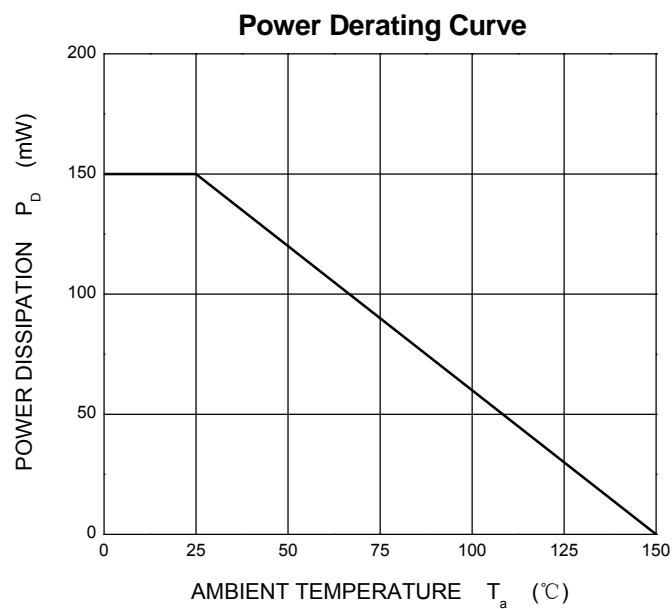
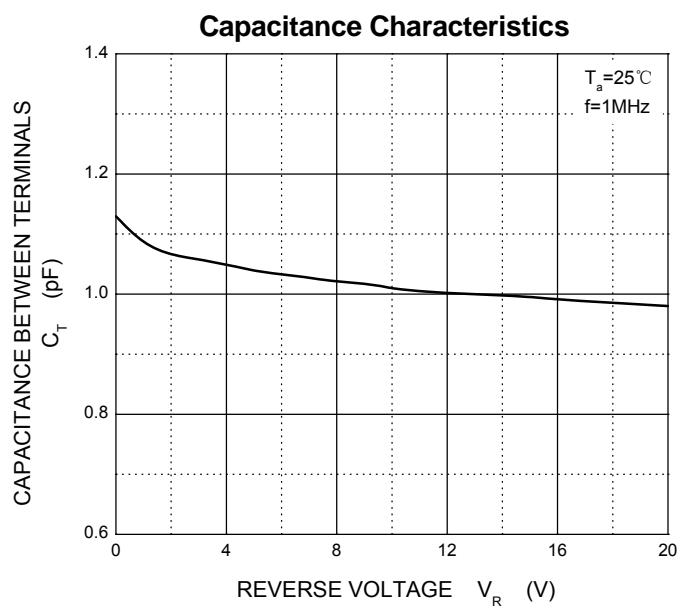
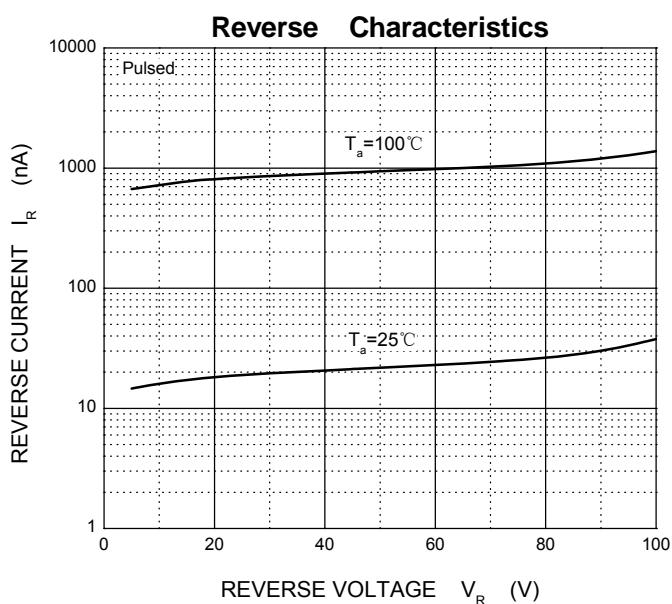
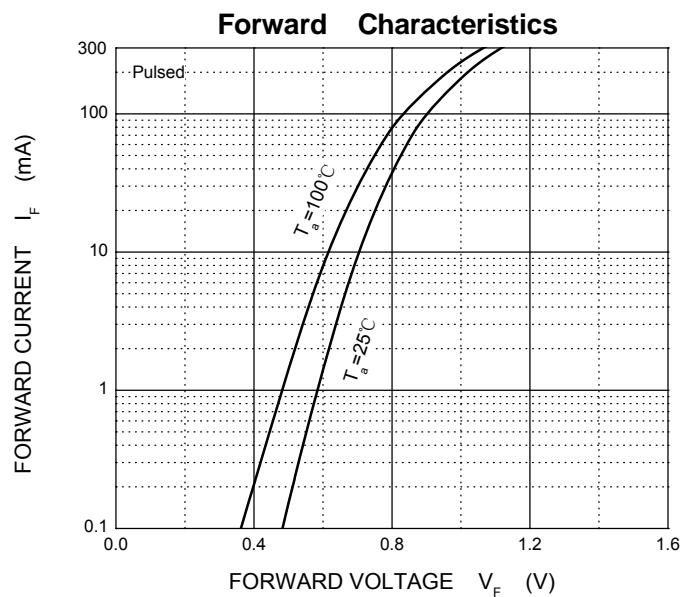


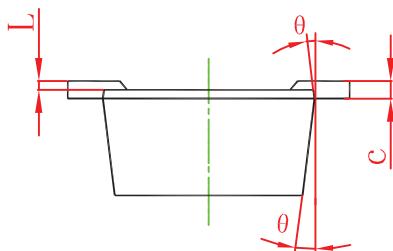
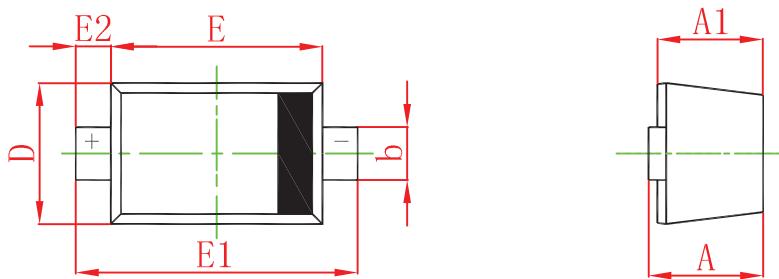
Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Peak Reverse Voltage	V _{RRM}		
Working Peak Reverse Voltage	V _{RWM}	75	V
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current	I _{FM}	500	mA
Average Rectified Output Current	I _O	250	mA
Non-Repetitive Peak Forward Surge Current @ t=8.3ms	I _{FSM}	2.0	A
Power Dissipation	P _d	150	mW
Thermal Resistance Junction to Ambient	R _{θJA}	833	°C/W
Operation Junction and Storage Temperature Range	T _J , T _{STG}	-55~+150	°C

ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise specified)

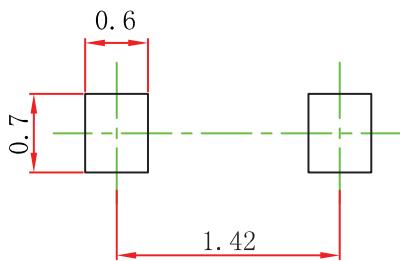
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	V _{(BR)1}	I _R =5μA	75			V
Reverse voltage	V _{(BR)2}	I _R =100μA	100			V
Reverse current	I _R	V _R =75V			1	μA
		V _R =20V			25	nA
Forward voltage	V _F	I _F =5mA			0.715	V
		I _F =10mA			0.855	V
		I _F =100mA			1	V
		I _F =150mA			1.25	V
Total capacitance	C _{tot}	V _R =0V,f=1MHz			4	pF
Reverse recovery time	t _{rr}	I _F =I _R =10mA, I _{rr} =0.1*I _R , R _L =100Ω			4	ns

Typical Characteristics



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.510	0.770	0.020	0.031
A1	0.500	0.700	0.020	0.028
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	0.750	0.850	0.030	0.033
E	1.100	1.300	0.043	0.051
E1	1.500	1.700	0.059	0.067
E2	0.200 REF		0.008 REF	
L	0.010	0.070	0.001	0.003
θ	7° REF		7° REF	

SOD-523 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.